

Special Issue

Semiconductor Sensor

Message from the Guest Editors

Sensors play an important role in advancing technology for various applications. We encourage authors to submit original research papers on various types of semiconductor-based sensors, not including photosensors. The types of sensors we are interested in for this Special Issue include but are not limited to chemical/gas, radiation, biological, stress, and motion sensors. The articles can be related to the fabrication, characterization, modeling and reliability of the sensor devices. The semiconductors can be elemental or any compound semiconductor. Articles on novel applications of the existing sensor devices are welcome as well.

Guest Editors

Prof. Dr. Mulpuri V Rao

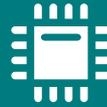
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Deadline for manuscript submissions

closed (15 March 2022)



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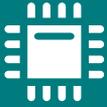


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About the Journal

Message from the Editor-in-Chief

Sensors is a leading journal devoted to fast publication of the latest achievements of technological developments and scientific research in the huge area of physical, chemical and biochemical sensors, including remote sensing and sensor networks. Both experimental and theoretical papers are published, including all aspects of sensor design, technology, proof of concept and application. *Sensors* organizes Special Issues devoted to specific sensing areas and applications each year.

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